

SPECIFICATION

1	Product:	Topview	5550	SMD LE	ED

② Part No: IWS-505-UB-K3

3 Customer:

<u>4</u> Date : 2008. 08. 06 Ver.1.1

Customer	
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Checked By	Checked By	Checked By	Checked By	Approval

Manufacturer: ITSWELL Co., LTD

Proposed By	Checked By Checked By		Checked By	Approval	
				APPROVED 308 7. 10 Q.A	

Comment							



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1. Features

- 3 chip high-Luminous intensity Chip LED
- 5.5 x 5.0 x 1.6 mm (L x W x H), 6-pin, small size surface mount type
- Wide Viewing angle
- · Long operating life

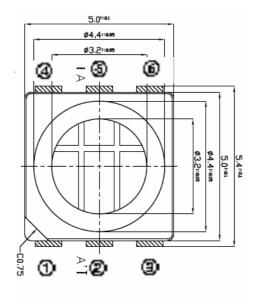
2. Applications

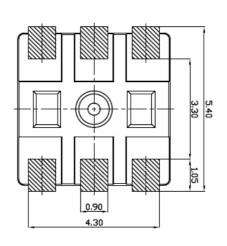
- Automotive: Backlight in dashboard and switch
- Lighting device: Indicator, lighting
- Camera flash, Hand Carrier Flash
- General use

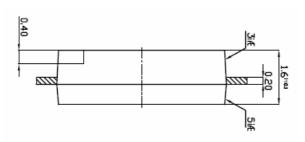
3. Outline Drawing and Dimension

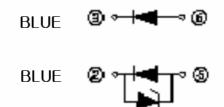
Unit: mm

Tolerance: ±0.1mm









Circuit diagram

BLUE ① → | • □ · □ · ②

Note

- 1. All dimensions are in millimeters
- 2. All dimensions without tolerances are for reference only

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4. Absolute Maximum Ratings(Ta = 25

Parameter	Symbol	Value	Unit
Power Dissipation	P _d	228	mW
Continuous Forward Current	I _F	30	mA
Peak Forward Current *1	I _{FP}	100	mA
Reverse Current	I _R	100	mA
Operating Temperature	T _{opr}	-30 ~ 85	°C
Storage Temperature	T _{stg}	-40 ~100	°C
Soldering Temperature	T _{sol}	260 (5sec)	°C

^{※1} Duty ratio = 1/10, Pulse width = 0.1ms

5. Electro-optical Characteristics (Ta = 25

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit.
Forward Voltage	V _F	I _F = 20 mA /Chip	3.0	3.4	3.6	V
Reverse Voltage	V_{RZ}	$I_R = 5 \text{ mA}$	0.7	0.8	1.5	V
Luminous Intensity *2	I_V	I _F = 20 mA /Chip	500	-	1100	mcd
Dominant Wavelength*3	W_{D}	I _F = 20 mA /Chip	450		470	
View angle *4	2 0 _{1/2}	I _F = 20 mA /Chip	-	120	-	0

^{*2} Luminous Intensity is tested by a tester calibrated by CAS 140B(CIE LED_B) and has an accuracy of 10%

5.1 Luminous Intensity Rank

Rank	Luminous Intensity (mcd)
А	500 ~ 700
В	700 ~ 900
С	900 ~ 1200

5.2 Forward Voltage

Rank	Forward Voltage (V)
а	3.0 ~ 3.2
b	3.2 ~ 3.4
С	3.4 ~ 3.6

5.3 Dominant Wavelength Rank

Rank	Dominant wavelength (nm)		
0	450~460		
1	460~470		

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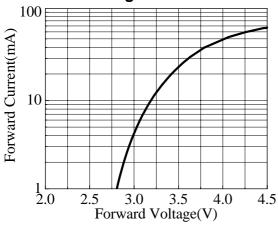
³ Dominant wavelength has an accuracy of ± 1 nm.

^{*4} Viewing angle is the angle until 50% of brightness measured from the front part of LED.

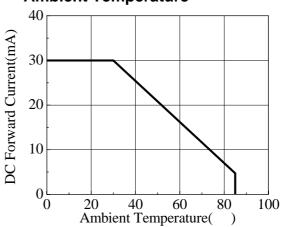


6. Typical Characteristics Curves

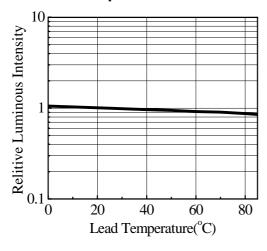
Forward Current vs. Forward Voltage



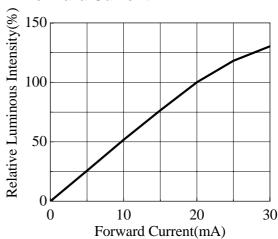
Forward Current vs. Ambient Temperature



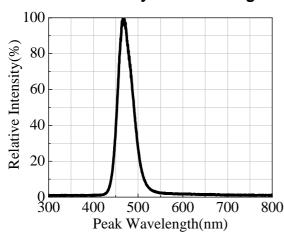
Relative Luminous Intensity vs. Ambient Temperature



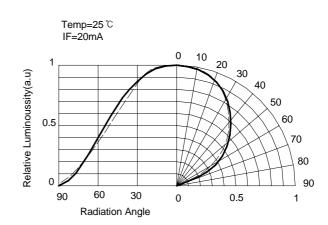
Relative Luminous Intensity vs. Forward Current



Relative Intensity vs. Wavelength



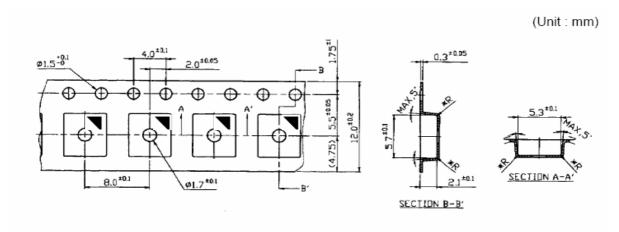
Radiation Diagram



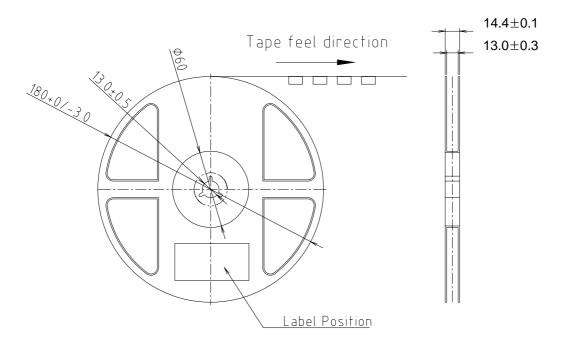


7. Dimension of Tape / Reel

7.1 Tape Dimension



7.2 Reel Dimension



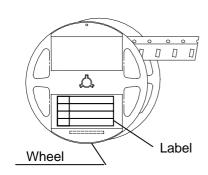
- Quantity: Product are packed in one taping reel of max. 1,000 pcs.
- ullet Cumulative Tolerance : Cumulative Tolerance/10 pitches to be ± 0.2 mm
- Adhesion Strength of Cover Tape: Adhesion strength to be 0.1-0.7N when the over tape is turned off from the carrier tape at 10° angle to be the carrier tape.
- Packaging: P/N, Manufacturing data Code No. and quantity to be indicated on a damp proof Package.

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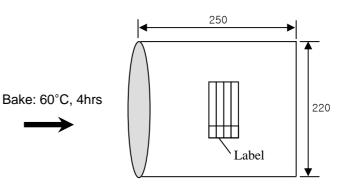
8. Packing Dimension

Unit:mm



Diameter: 180 mm Width: 12 mm

5550 ⇒ 1,000 pcs/Reel

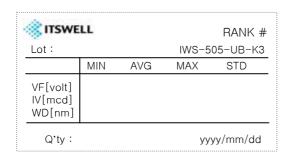


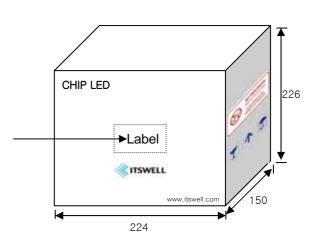
Shield Bag(Polyester/Al/LDPE)
1 Reel / Bag (T = 0.1 mm) with Silica gel



Al Pack Label, Reel Label

 (70×37)





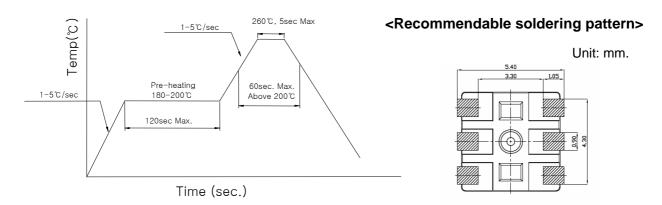
Maximum 10 Bags / 1 Inner Box 5750 ⇒8,000 pcs/ 1 Inner Box



9. Precaution in use

9.1 Soldering Conditions

- When soldering Power SMD, Heat may affect the electrical and optical characteristics of the LEDs.
- In soldering, do not stress the lead frame and the resin part under the high temperature.
- The silicone part should be protected from mechanical stress or vibration until the Power SMD return to room temperature after soldering.
- Preliminary heating to be at 200 max. for 120 Seconds max.
- Soldering heat to be at 260 max. for 5sec. Max.
- For manual Soldering is Not more than 3sec @MAX350 , under soldering iron



9.2 Storage

Use with 7days after opening packing. Store in 10 to 30 Power SMD lead frames are plated silver. The silver surface may be affected by environment which contain corrosive gases and so on. Please avoid condition which may cause the Power SMD to corroded, tarnish or discolor.

9.3 Static Electricity

- Static electricity or surge voltage damages the Power SMD. It is recommended that a wrist band or an anti-electrostatic glove be used when handling the LEDs.
- A tip soldering iron is requested to be grounded. An ionizer should also be installed where risk of static.
- All devices, equipment and machinery must be properly grounded (via 1M). It is recommended that measures be taken against surge voltage to the equipment that mounts the Power SMD.

9.4 Cleaning

- Isopropyl Alcohol or Ethylene Alcohol is recommended in 5 minutes at room temperature.
 Don't use unspecified chemical may cause crack or haze on the surface of the epoxy resin.
- Before cleaning, a pre-test should be done to confirm whether any damage to the LED will occur.
- Freon solvents should not be used to clean the LEDs because of worldwide regulations.



10. Reliability

10.1 Reliability Test Item

Test Items	Test Conditions	Notes
High Temperature Storage	100℃ , 500hr.	0/32
Low Temperature Storage	-30℃, 500hr.	0/32
Temp. Humidity Storage	60℃, 90% RH, 500hr.	0/32
Steady State Operating life	25℃, 30mA / Chip, 500hr.	0/32
High Temperature Operating Life	85℃, 5mA / Chip, 500hr	0/32
Low Temperature Operating Life	-30°C , 20mA / Chip, 500hr.	0/32
Steady State Operating life Of High Humidity Heat	60℃, 90% RH, 15mA /Chip, 300hr.	0/32
Temperature Cycle	-40 $^{\circ}$ (30min) \rightarrow 25 $^{\circ}$ (5min.) \rightarrow 100 $^{\circ}$ (30min.) 25 $^{\circ}$ (5min.) , 100 cycle	0/22
ESD	HBM, 100pF, 1.5kohm, 3 times	0/22

10.2 Criteria for Judging the Damage

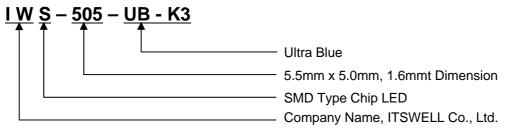
Items	Test Conditions	Criteria for judgment
Luminous Intensity (I _V)	I _F =20 mA / Chip	> 70% of S
Forward Voltage (V _F)	I _F =20 mA / Chip	Less than 120% of U
Reverse Voltage (V _{ZR})	I _R =5 mA / Chip	Less than 120% of U

^{*} U means the upper limit of specified characteristics, S means initial value.

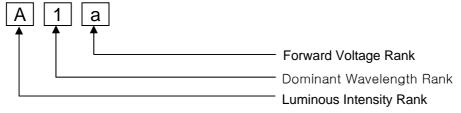
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11. Part Name Description



12. Rank Description



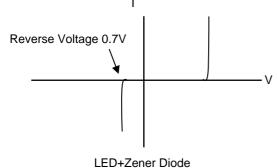
13. Attention : Electric Static Discharge (ESD) Protection





The symbol shown on the page herein to introduce 'Electro-Optical Characteristics'. ESD protection for GaP and AlGaAs is based chips is still Necessary even though they are safe in low static-electric discharge. Material in AlInGaP, GaP, or/and InGaN based chips are STATIC SENSITIVE devices. ESD protection has to considered and taken in the initial design stage. If manual work/process is needed, please ensure the device is well protective From ESD during all the process. LED's ESD Level is 'Class II' and The range of Forward Voltage is 2000V ~ 3999V.

After opening the package, the LED's should be kept at 30 , 70%RH or less. The LEDs must be dip soldered within seven days (168 hours) after opening the moisture-proof packing. It is better not to use different rank LEDs. If use mixed rank, could not attain your object for highest quality of products.



- Do not apply reverse voltage more than 0.7V.
- Product with Zener Diode is needed to discriminate the characteristics of product by fixing current and measuring voltage.

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Spec. Review History

Review Ver.	Date	Correction List	Etc.
Ver 1.0	2007.05.10	Establish	
Ver 1.1	2008.08.06	L/F 변경	

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